# imall

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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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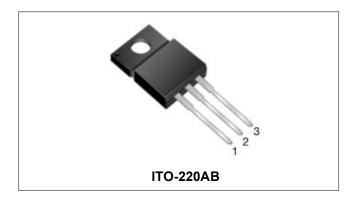
### MBRF3035CT MBRF3040CT MBRF3045CT



Data Sheet N0831 Rev. B

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# MBRF3035CT /MBRF3040CT /MBRF3045CT SCHOTTKY RECTIFIER



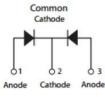
#### Features

- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

# Circuit Diagram



#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	-	35	MBRF3035CT	
Working Peak Reverse Voltage	VRWM		40	MBRF3040CT	V
DC Blocking Voltage	VR		45	MBRF3045CT	
Average Bestified Ferward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc =123 °C,	15(per leg) 30(per device)		A
Average Rectified Forward Current		rectangular wave form			
Peak One Cycle Non-Repetitive	Isou	8.3 ms, half Sine pulse		240	Δ
Surge Current(Per Leg)	IFSM				A

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 15 A, Pulse, TJ = 25 °C @ 30 A, Pulse, TJ = 25 °C	0.60 0.8	0.70 0.84	V
	V <sub>F2</sub>	@ 15 A, Pulse, TJ = 125 °C @ 30 A, Pulse, TJ = 125 °C	0.55 0.73	0.57 0.75	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R$ = rated V <sub>R</sub> ,T <sub>C</sub> = 25 °C	0.03	1.0	mA
	I <sub>R2</sub>	@ $V_R$ = rated $V_{R}$ , $T_C$ = 125 °C	15	100	mA
Junction Capacitance(Per Leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	300	800	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	7.5	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

\* Pulse width < 300 µs, duty cycle < 2%

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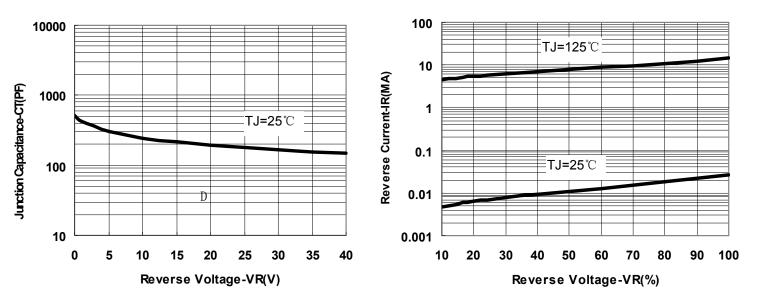
# MBRF3035CT MBRF3040CT MBRF3045CT

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## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	2.4	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

#### **Ratings and Characteristics Curves**







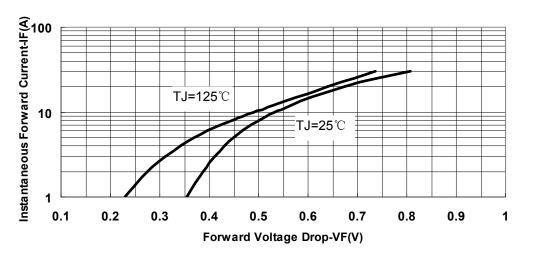


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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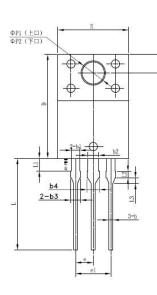


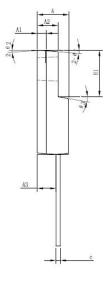
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#### **Mechanical Dimensions ITO-220AB**

-

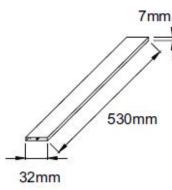




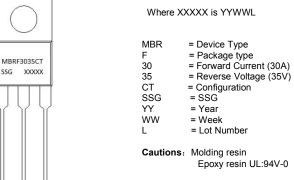
SYMBOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
A	4.30	4.50	4.70		
A1	1.10	1.30	1.50		
A2	2.80	3.00	3.20		
A3	2.50	2.70	2.90		
b	0.50	0.60	0.75		
b1	1.10	1.20	1.35		
b2	1.50	1.60	1.75		
b3	1.20	1.30	1.45		
b4	1.60	1.70	1.85		
с	0.50	0.60	0.75		
D	14.80	15.00	15.20		
E	9.96	10.16	10.36		
е		2.55			
e1		5.10			
H1	6.50	6.70	6.90		
L	12.70	13.20	13.70		
L1	1.60	1.80	2.00		
L2	0.80	1.00	1.20		
L3	0.60	0.80	1.00		
<b>ΦΡ1(上口)</b>	3.30	3.50	3.70		
<b>ΦΡ2</b> (下口)	2.99	3.19	3.39		
Q	2.50	2.70	2.90		
Θ1		5°			
Θ2		4°			
Θ3		10°			
Θ4		5°			
Θ5		5°			

# 

#### **Tube Specification**



# Marking Diagram



#### **Ordering Information**

Device	Package	Shipping
MBRF3035(40)(45)CT	ITO-220AB (Pb-Free)	50 pcs/ tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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#### Technical Data Data Sheet N0831 Rev. B

# MBRF3035CT MBRF3040CT MBRF3045CT



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